

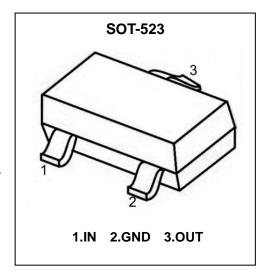
DTC114EE

Digital Transistor

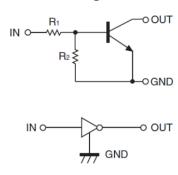
DTC114EE Digital Transistor(NPN)

Feature

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors
- The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input .They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy



Schematic diagram





ABSOLUTE MAXIMUM RATINGS (T_a=25℃ unless otherwise noted)

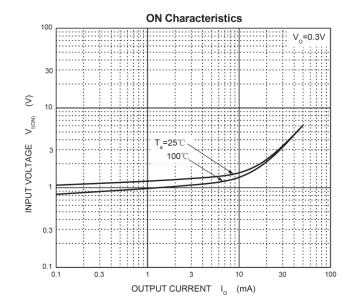
| Symbol | Value | Unit |
|------------------|--|---|
| Vcc | 50 | V |
| Vin | -10~+40 | V |
| lo | 100 | mA |
| PD | 150 | mW |
| TJ | 125 | $^{\circ}$ C |
| T _{STG} | -45 ~ +125 | $^{\circ}\!\mathbb{C}$ |
| | Vcc V _{IN} I _O P _D | Vcc 50 V _{IN} -10~+40 Io 100 P _D 150 T _J 125 |

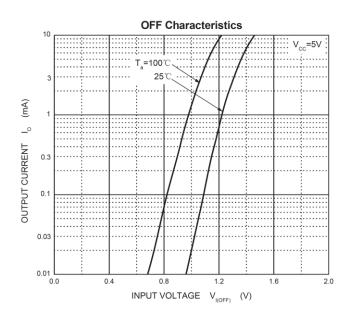
ELECTRICAL CHARACTERISTICS (Ta=25℃ unless otherwise noted)

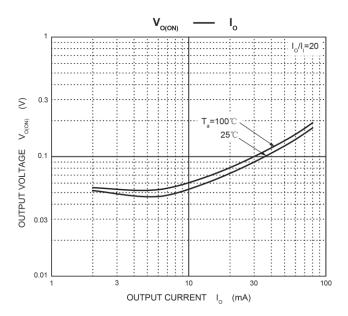
| Parameter | Symbol | Test Condition | Min | Туре | Max | Unit |
|----------------------|---------------------------------|---|-----|------|------|------|
| Input voltage | $V_{I(off)}$ | Vcc=5V , Io=100μA | 0.5 | | | V |
| | $V_{I(on)}$ | Vo=0.3V , Io=10mA | | | 3 | V |
| Output voltage | V _{O(on)} | Io=10mA ,I _I =0.5mA | | | 0.3 | V |
| Input current | lı | V _I =5V | | | 0.88 | mA |
| Output current | I _{O(off)} | Vcc=50V , Vi=0V | | | 0.5 | μΑ |
| DC current gain | Gı | V ₀ =5V ,I ₀ =5mA | 30 | | | |
| Input resistance | R ₁ | | 7 | 10 | 13 | kΩ |
| Resistance ratio | R ₂ / R ₁ | | 0.8 | 1 | 1.2 | |
| Transition frequency | f⊤ | Vo=10V,Io=5mA,f=1MHz | | 250 | | MHz |

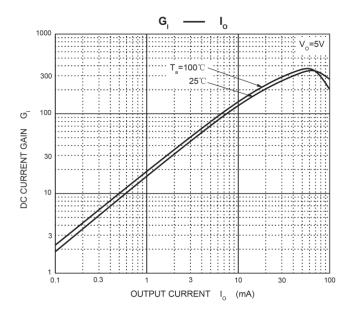


Typical Characteristics



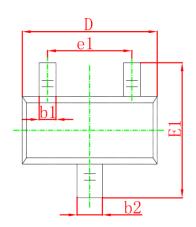


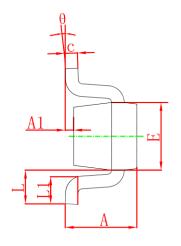


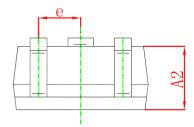




SOT-523 Package Information







| Symbol | Dimensions In Millimeters | | Dimensions In Inches | | |
|--------|---------------------------|-------|----------------------|-------|--|
| | Min. | Max. | Min. | Max. | |
| Α | 0.700 | 0.900 | 0.028 | 0.035 | |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 | |
| A2 | 0.700 | 0.800 | 0.028 | 0.031 | |
| b1 | 0.150 | 0.250 | 0.006 | 0.010 | |
| b2 | 0.250 | 0.350 | 0.010 | 0.014 | |
| С | 0.100 | 0.200 | 0.004 | 0.008 | |
| D | 1.500 | 1.700 | 0.059 | 0.067 | |
| E | 0.700 | 0.900 | 0.028 | 0.035 | |
| E1 | 1.450 | 1.750 | 0.057 | 0.069 | |
| е | 0.500 TYP. | | 0.020 TYP. | | |
| e1 | 0.900 | 1.100 | 0.035 | 0.043 | |
| Ĺ | 0.400 REF. | | 0.016 REF. | | |
| L1 | 0.260 | 0.460 | 0.010 | 0.018 | |
| θ | 0° | 8° | 0° | 8° | |

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